Anomalous Interaction Dependence in Magnetism of Graphene Nanoribbons with Zigzag Edges

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Properties in magnetic ordered states of graphene nanoribbons with zigzag shaped edges are investigated by applying mean-field approximation to the Hubbard model with on-site repulsion U. We observe that magnetic moments and critical temperature show anomalous power-law dependences as a function of U; the actual values of the power are determined by only the width of ribbons. Such singular behaviours are found to be due to localized nature of the electronic states close to Fermi energy.

KEYWORDS: graphene nanoribbon, zigzag shaped edges, edge states, magnetism

1. Introduction

Graphene-based materials with nano-meter sizes have been attracting much attention due to their possibilities as new potential devices in application as well as novel stages for emergence of exotic phenomena in fundamental science. Especially, the graphene nanoribbon with zigzag shaped edges, which is abbreviated to zigzag GNR in the following, is known to have fascinating peculiar properties as follows.^{1–7)} The zigzag GNR has a metallic band structure irrespective of the width N in the sense that the energy gap does not appear at the Fermi energy in the absence of doping, E=0. However, unlike usual metals, the asymptotic form of the energy dispersion near E=0 is written as $E\propto \pm |k-\pi/a|^N$, and the Fermi velocity vanishes for $N\geq 2$ where a and N express the lattice spacing and the width of the ribbon (see Fig.1), respectively. Such characteristic properties are due to the fact that the one-particle states near E=0 are well localized around zigzag edges, i.e., the states close to E=0 are so called edge states. The zigzag edges and the localized states around them have been observed by scanning tunneling microscopy and spectroscopy.^{8–13)}

Magnetic properties of the zigzag GNR have been investigated by applying mean-field approximation to the Hubbard model with on-site repulsion $U^{2,14-17)}$ and by the first principles calculation. ^{18–22)} It has been found that the large spontaneous magnetic moments appear at the zigzag edges, which is originated from the edge states. The magnetic moments align ferromagnetically at each edge but with the opposite direction between the edges. In addition, the magnetic order appears under the infinitesimal on-site repulsion; the conclusion is different from the case for graphene sheets where the finite amount of U is necessary for emergence of the antiferromagnetic state. The spin excitations ^{14,22)} and

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the interedge superexchange interaction¹⁷⁾ have been calculated based on the magnetic structure introduced above. The treatments beyond the mean-field approximation, in which quantum fluctuation is fully taken into account, have been carried out.^{23–25)} The ground state is found to be Mott insulator with charge gap, and the field theoretical approach demonstrates that the Heisenberg model on the zigzag GNR expressing the spin excitation belongs to the same universality class as spin 1/2 square ladders²³⁾ (gapped for even number legs, gapless for odd number of legs). The result is confirmed by numerical calculation.²⁵⁾

In ordered states seen in electron systems, usually, the order parameter shows exponential dependence as a function of the coupling constant; this fact is due to the finite density of states (DOS) at the Fermi energy. On the other hand, the DOS of the zigzag GNR show divergence at Fermi energy. Therefore, in the magnetic ordered state of the zigzag GNR, unusual dependence of the spontaneous magnetic moments as a function of U is expected. In the present work, we study properties of the magnetic ordered states in the zigzag GNR by applying the mean-field approximation to the Hubbard model. We focus on interaction dependence of spontaneous magnetic moments and critical temperature. It is found that these quantities show anomalous power-law dependences and the actual values of the power are determined by only the width N of the ribbons. We clarify that the unusual band structure close to Fermi energy gives rise to such singular behaviours.

2. Model

The graphene nanoribbons with zigzag shaped edges we study are illustrated in a schematic way in Fig. 1. Figs. 1 (a) and (b) show the zigzag GNRs with the width N being even and odd, respectively.

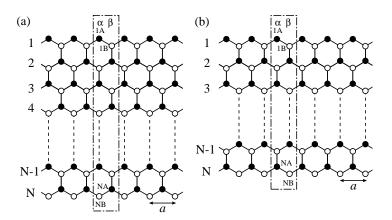


Fig. 1. Schematic illustration of zigzag GNRs consisting of N legs with N= even (a) and N= odd (b). Here, the rectangle written by the dash dotted line shows the unit cell and a is the lattice spacing. The filled (open) circles express the A (B) sublattices. The two types of slices in the unit cell are denoted as α and β .

In the respective figures, the rectangle written by the dash dotted line and a express the unit cell and the lattice spacing, respectively. The filled (open) circles indicate the A (B) sublattices. In the unit cell,

there are two types of carbon slices; those are denoted as α and β .

The Hamiltonian we consider reads $\mathcal{H}=\mathcal{H}_k+\mathcal{H}_{int},$ where

$$\mathcal{H}_{k} = -t \sum_{I,\sigma} \sum_{i=1}^{N} \left\{ c_{iB,\sigma}^{\dagger}(I) c_{iA,\sigma}(I) + c_{iA,\sigma}^{\dagger}(I) c_{iB,\sigma}(I + (-1)^{i}) + \text{h.c.} \right\}$$
$$-t \sum_{I,\sigma} \sum_{i=1}^{N-1} \left\{ c_{iB,\sigma}^{\dagger}(I) c_{(i+1)A,\sigma}(I) + \text{h.c.} \right\}, \tag{1}$$

$$\mathcal{H}_{\text{int}} = \frac{U}{2} \sum_{I,\sigma} \sum_{i=1}^{N} \left\{ n_{iA,\sigma}(I) n_{iA,-\sigma}(I) + n_{iB,\sigma}(I) n_{iB,-\sigma}(I) \right\}, \tag{2}$$

where t is the hopping between the nearest neighbor carbon atoms. Here $c_{iX,\sigma}^{\dagger}(I)$ is the creation operator of an electron with the spin $\sigma=\pm$ ($\sigma=+/-$ expresses \uparrow/\downarrow spin state) at the iX site in the I-th cell, and $n_{iX,\sigma}(I)=c_{iX,\sigma}^{\dagger}(I)c_{iX,\sigma}(I)$ ($i=1,\cdots,N$ and X=A,B unless explicitly noted in the following). The mean-field approximation is applied to $\mathcal{H}_{\rm int}$ as

$$\mathcal{H}_{\text{int}} \to \mathcal{H}_{\text{int}}^{\text{MF}} = \frac{U}{2} \sum_{I,\sigma} \sum_{i=1}^{N} \left\{ (n_{iA} - \sigma m_{iA}) c_{iA,\sigma}^{\dagger}(I) c_{iA,\sigma}(I) + (n_{iB} - \sigma m_{iB}) c_{iB,\sigma}^{\dagger}(I) c_{iB,\sigma}(I) \right\}, \tag{3}$$

where $n_{iX} = \sum_{\sigma} \langle n_{iX,\sigma}(I) \rangle$ and $m_{iX} = \sum_{\sigma} \sigma \langle n_{iX,\sigma}(I) \rangle$ are the charge and spin order parameters with $\langle \cdots \rangle$ being the thermal average. We should note that the magnetic solution as well as the paramagnetic one in the neutral system has $n_{iA} = n_{iB} = 1$ due to the particle-hole symmetry. Therefore, in the following, we neglect the terms including the charge order parameters for simplicity since those renormalize the chemical potential. As a result, the Hamiltonian under the mean-field approximation is written as follows,

$$\mathcal{H}^{\mathrm{MF}} = \sum_{k,\sigma} \Psi^{\dagger}(k,\sigma) \left\{ h_{\mathbf{k}}(k) + h_{\mathrm{int}}^{\mathrm{MF}}(\sigma) \right\} \Psi(k,\sigma), \tag{4}$$

where $\Psi^\dagger(k,\sigma)=(c_{1A,\sigma}^\dagger(k),c_{1B,\sigma}^\dagger(k),\cdots,c_{NA,\sigma}^\dagger(k),c_{NB,\sigma}^\dagger(k))$. Here $h_{\mathbf{k}}(k)$ and $h_{\mathrm{int}}^{\mathrm{MF}}(\sigma)$ are the $2N\times 2N$ matrices,

$$h_{k}(k) = -t \times \begin{pmatrix} 0 & \gamma_{k} & 0 & 0 & \cdots & 0 & 0 & 0 & 0 \\ \gamma_{k} & 0 & 1 & 0 & \cdots & 0 & 0 & 0 & 0 \\ 0 & 1 & 0 & \gamma_{k} & \cdots & 0 & 0 & 0 & 0 \\ 0 & 0 & \gamma_{k} & 0 & \cdots & 0 & 0 & 0 & 0 \\ \vdots & \vdots & \vdots & \vdots & \ddots & \vdots & \vdots & \vdots & \vdots \\ 0 & 0 & 0 & 0 & \cdots & 0 & \gamma_{k} & 0 & 0 \\ 0 & 0 & 0 & 0 & \cdots & \gamma_{k} & 0 & 1 & 0 \\ 0 & 0 & 0 & 0 & \cdots & 0 & 1 & 0 & \gamma_{k} \\ 0 & 0 & 0 & 0 & \cdots & 0 & 0 & \gamma_{k} & 0 \end{pmatrix},$$
 (5)

$$h_{\text{int}}^{\text{MF}}(\sigma) = -\sigma \frac{U}{2} \times \text{diag}(m_{1A}, m_{1B}, \cdots, m_{NA}, m_{NB}), \qquad (6)$$

where $\gamma_k = 2\cos(ka/2)$. Here, the Fourier transformations

$$c_{iA,\sigma}(I) = \frac{1}{\sqrt{N_L}} \sum_{k} e^{ik(x_I + (-1)^i a/4)} c_{iA,\sigma}(k),$$
 (7)

$$c_{iB,\sigma}(I) = \frac{1}{\sqrt{N_L}} \sum_{k} e^{ik(x_I - (-1)^i a/4)} c_{iB,\sigma}(k),$$
 (8)

are introduced with N_L being the total number of the unit cell in the system and $x_I = Ia$. We note that $h_k(k)$ becomes the real and symmetric matrix owing to the choice of the Fourier transformation, eqs. (7) and (8). The 2N order parameters m_{iA} and m_{iB} are determined self-consistently by

$$m_{iA} = \frac{1}{N_L} \sum_{k,\sigma} \sum_{j=1}^{2N} \sigma \left\{ \left[\vec{v}_{\sigma}^{(j)}(k) \right]_{2i-1} \right\}^2 f(E_{\sigma}^{(j)}(k)), \tag{9}$$

$$m_{iB} = \frac{1}{N_L} \sum_{k,\sigma} \sum_{j=1}^{2N} \sigma \left\{ \left[\vec{v}_{\sigma}^{(j)}(k) \right]_{2i} \right\}^2 f(E_{\sigma}^{(j)}(k)), \tag{10}$$

where f(E) is the Fermi function defined by $f(E)=1/\{\exp(E/T)+1\}$ with T being the temperature. Here $E_{\sigma}^{(j)}(k)$ is an eigenvalue of the matrix $h_{\mathbf{k}}(k)+h_{\mathrm{int}}^{\mathrm{MF}}(\sigma)$ and the corresponding eigenvector is expressed by $\vec{v}_{\sigma}^{(j)}(k)$, the l-th $(l=1,2,\cdots,2N)$ element of which is a real number and written as $\left[\vec{v}_{\sigma}^{(j)}(k)\right]_{l}$. The energy per an atom $\epsilon(U)$ is given by

$$\epsilon(U) = \frac{1}{2N_L N} \sum_{k,\sigma} \sum_{j=1}^{2N} E_{\sigma}^{(j)}(k) f(E_{\sigma}^{(j)}(k)) + \frac{U}{8N} \sum_{i=1}^{N} \left(m_{iA}^2 + m_{iB}^2 \right). \tag{11}$$

3. Results and Discussions

We can obtain the two kinds of self-consistent solutions; one expresses the antiferromagnetic (AF) state which satisfies $m_{iA} = -m_{(N-i+1)B}$ and the other is the ferromagnetic (F) state with $m_{iA} = m_{(N-i+1)B}$. The magnetic moment at each site and the energy difference $\Delta \epsilon(U) = \epsilon(U) - \epsilon(0)$ in the both states are shown in Figs. 2 (a) and (b), respectively, for the N=3 system at the absolute zero temperature. In each figure, the quantities in the AF state and those in the F state are expressed by the solid and dotted curves, respectively. Though difference between m_{2A} and m_{3A} (m_{1B} and m_{2B}) in the AF state is not clearly seen in Fig. 2 (a), there exists the significant difference between the both quantities. As we expected, the AF state is more stable than the F state. Then, we concentrate on the AF state unless noted. Note that the energy difference per an atom between the AF state and the F state $\epsilon_{AF}(U) - \epsilon_{F}(U)$ becomes smaller with increasing the width N. This fact seems to indicate that difference in the energy is mainly originated from that in the local spin structure, for example, the spin configuration at the bond in the center of the ribbon, i.e., nA-nB bond for N=2n-1 and nB-(n+1)A for N=2n. Qualitative discrepancies between the N=0 odd zigzag GNR and the N=0 even one have been observed in transport properties n0 and persistent currents.

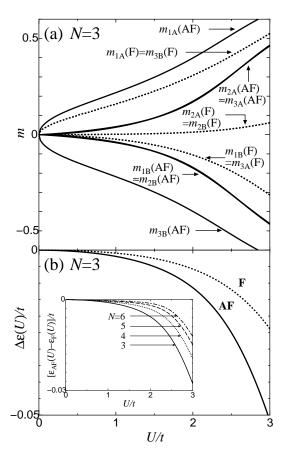


Fig. 2. Self-consistent solutions of the AF state and the F state for the N=3 zigzag GNR; magnetic moments at each atom in the unit cell, m_{iA} and m_{iB} , (a) and energy difference $\Delta\epsilon(U)=\epsilon(U)-\epsilon(0)$ (b) where $\epsilon(U)$ is defined in eq. (11). In each figure, the solid and dotted curves express the quantities in the AF state and those for the F state, respectively. The inset in (b) shows the energy difference between the AF state and the F state, $\epsilon_{\rm AF}(U)-\epsilon_{\rm F}(U)$, for several choices of N.

We investigate in detail the magnetic moment at the zigzag edges, which is far largest than the others, and then considered to dominate the magnetic properties as far as $U/t \ll 1$. The magnetic moment at the 1A site m_{1A} of the AF state is shown as a function of U/t close to U/t = 0 in Fig. 3 for $N = 2, 3, \cdots, 10$. We can see that the magnetic moment m_{1A} behaves as $m_{1A} \propto (U/t)^{1/(N-1)}$, i.e., the quantity shows power-law dependences and the actual value of the power is determined by the width N. The result seems to be anomalous because the order parameters of the usual ordered states realized in the electronic systems are known to show exponential dependences as a function of the coupling constant for weak coupling limit. Actually, in the case of N=1 which is nothing but the usual one-dimensional system, $m_{1A}=-m_{1B}\simeq 16(t/U)\exp(-2\pi t/U)$ as long as $U/t\ll 1$.

Next we investigate the critical temperature T_c of the AF state, which is also known to show exponential dependence as a function of the coupling constant in the usual ordered state. Fig. 4 shows the critical temperature as a function of U/t close to U/t=0. Here, the power-law dependence is

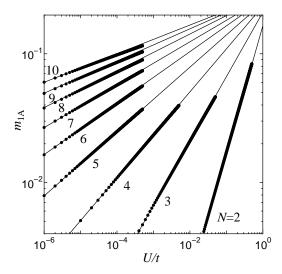


Fig. 3. Magnetic moment at the 1A site, m_{1A} , of the AF state as a function of U/t for the several choices of N. The solid lines express the fitting by $m_{1A} \propto (U/t)^{1/(N-1)}$.

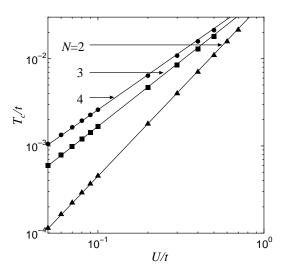


Fig. 4. Critical temperature T_c of the AF state as a function of U/t for the several choices of N. The solid lines express the fitting by $T_c/t \propto (U/t)^{N/(N-1)}$.

also seen in the critical temperature as $T_c \propto (U/t)^{N/(N-1)}$. The actual value of the power in T_c is different from that in $m_{1\rm A}$. However, it can be well understood by the simple dimension analysis, $T_c \sim U \times m_{1\rm A}$, with considering that the AF transition is dominated by the edges states.

Here, we explore the critical temperature from divergence of the magnetic susceptibility. The instability toward the AF state and that toward the F state will be investigated. In the presence of the external magnetic field H_{iX} , which does not depend on an index of the unit cell I but does depend on the location in the unit cell, the linear response theory results in the magnetic moments, m_{iA} and m_{iB}

as

$$m_{iA} = \sum_{i'=1}^{N} \left\{ \chi_{iA,i'A}^{0} H_{i'A}^{\text{eff}} + \chi_{iA,(N-i'+1)B}^{0} H_{(N-i'+1)B}^{\text{eff}} \right\},$$
(12)

$$m_{(N-i+1)B} = \sum_{i'=1}^{N} \left\{ \chi_{(N-i+1)B,i'A}^{0} H_{i'A}^{\text{eff}} + \chi_{(N-i+1)B,(N-i'+1)B}^{0} H_{(N-i'+1)B}^{\text{eff}} \right\}, \tag{13}$$

where $H_{iX}^{\text{eff}} = H_{iX} + U m_{iX}/2$ is the effective magnetic field at the iX cite. The quantities $\chi^0_{iX,i'X'} = \lim_{q\to 0} \lim_{\omega_n\to 0} \chi^0_{iX,i'X'}(q,\mathrm{i}\omega_n)$ (X,X'=A,B) is the susceptibility of the non-interacting system:

$$\chi_{iA,i'A}^{0}(q,i\omega_{n}) = -\frac{2}{N_{L}} \sum_{k} \sum_{j,j'=1}^{2N} e^{iq\left\{(-1)^{i} - (-1)^{i'}\right\} a/4} \frac{f(E_{0}^{(j)}(k)) - f(E_{0}^{(j')}(k+q))}{i\omega_{n} + E_{0}^{(j)}(k) - E_{0}^{(j')}(k+q)}$$

$$\times \left[\vec{v}_{0}^{(j)}(k)\right]_{2i'-1} \left[\vec{v}_{0}^{(j)}(k)\right]_{2i-1} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i-1} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i'-1}, \qquad (14)$$

$$\chi_{iA,i'B}^{0}(q,i\omega_{n}) = -\frac{2}{N_{L}} \sum_{k} \sum_{j,j'=1}^{2N} e^{iq\left\{(-1)^{i} + (-1)^{i'}\right\} a/4} \frac{f(E_{0}^{(j)}(k)) - f(E_{0}^{(j')}(k+q))}{i\omega_{n} + E_{0}^{(j)}(k) - E_{0}^{(j')}(k+q)}$$

$$\times \left[\vec{v}_{0}^{(j)}(k)\right]_{2i'} \left[\vec{v}_{0}^{(j)}(k)\right]_{2i-1} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i-1} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i'}, \qquad (15)$$

$$\chi_{iB,i'A}^{0}(q,i\omega_{n}) = -\frac{2}{N_{L}} \sum_{k} \sum_{j,j'=1}^{2N} e^{iq\left\{-(-1)^{i} - (-1)^{i'}\right\} a/4} \frac{f(E_{0}^{(j)}(k)) - f(E_{0}^{(j')}(k+q))}{i\omega_{n} + E_{0}^{(j)}(k) - E_{0}^{(j')}(k+q)}$$

$$\times \left[\vec{v}_{0}^{(j)}(k)\right]_{2i'-1} \left[\vec{v}_{0}^{(j)}(k)\right]_{2i} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i'-1}, \qquad (16)$$

$$\chi_{iB,i'B}^{0}(q,i\omega_{n}) = -\frac{2}{N_{L}} \sum_{k} \sum_{j,j'=1}^{2N} e^{iq\left\{-(-1)^{i} + (-1)^{i'}\right\} a/4} \frac{f(E_{0}^{(j)}(k)) - f(E_{0}^{(j')}(k+q))}{i\omega_{n} + E_{0}^{(j)}(k) - E_{0}^{(j')}(k+q)}$$

$$\times \left[\vec{v}_{0}^{(j)}(k)\right]_{2i'} \left[\vec{v}_{0}^{(j)}(k)\right]_{2i} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i} \left[\vec{v}_{0}^{(j')}(k+q)\right]_{2i'}, \qquad (17)$$

with $E_0^{(j)}(k)$ $(j=1,\cdots,2N)$ being the eigenvalue of $h_k(k)$ and $\vec{v}_0^{(j)}(k)$ being the eigenvector corresponding to it. Namely, the element of $\vec{v}_0^{(j)}(k)$ expresses the amplitude of the j-th eigenfunction in the transverse direction in the non-interacting case.

In the F state, the magnetic moments satisfy the configuration $m_{iA} = m_{(N-i+1)B}$, whereas $m_{iA} = -m_{(N-i+1)B}$ is realized in the AF state. In order to lead to such a magnetic structure, the effective external field should satisfy $H_{iA}^{\text{eff}} = H_{(N-i+1)B}^{\text{eff}}$ ($H_{iA}^{\text{eff}} = -H_{(N-i+1)B}^{\text{eff}}$) for the F (AF) state. Based on the above consideration, eqs. (12) or (13) are rewritten as follows,

$$\vec{m}_A = \tilde{\chi}_{F/AF} \vec{H}_A,\tag{18}$$

$$\tilde{\chi}_{F/AF} = \left(\tilde{1} - \frac{U}{2}\tilde{\chi}_{F/AF}^{0}\right)^{-1}\tilde{\chi}_{F/AF}^{0},\tag{19}$$

where $\vec{m}_A = (m_{1A}, m_{2A}, \cdots, m_{NA})^t$, $\vec{H}_A = (H_{1A}, H_{2A}, \cdots, H_{NA})^t$ and $\tilde{1}$ is the $N \times N$ unit

matrix. Here, $\tilde{\chi}^0_F$ and $\tilde{\chi}^0_{AF}$ are the $N \times N$ matrices whose element is defined as

$$\begin{split} \left[\tilde{\chi}_{F/AF}^{0}\right]_{ii'} &= \chi_{iA,i'A}^{0} \pm \chi_{iA,(N-i'+1)B}^{0} \\ &= -\frac{2}{N_{L}} \sum_{k} \sum_{j,j'=1}^{2N} \lim_{q \to 0} \frac{f(E_{0}^{(j)}(k)) - f(E_{0}^{(j')}(k+q))}{E_{0}^{(j)}(k) - E_{0}^{(j')}(k+q)} \\ &\times \left[\vec{v}_{0}^{(j)}(k)\right]_{2i-1} \left[\vec{v}_{0}^{(j')}(k)\right]_{2i-1} \\ &\times \left(\left[\vec{v}_{0}^{(j)}(k)\right]_{2i'-1} \left[\vec{v}_{0}^{(j')}(k)\right]_{2i'-1} \pm \left[\vec{v}_{0}^{(j)}(k)\right]_{2(N-i'+1)} \left[\vec{v}_{0}^{(j')}(k)\right]_{2(N-i'+1)}\right), \quad (20) \end{split}$$

where the upper and lower sign correspond to $\left[\tilde{\chi}_F^0\right]_{ii'}$ and $\left[\tilde{\chi}_{AF}^0\right]_{ii'}$, respectively. The transition temperature is determined by $\det(\tilde{1}-(U/2)\tilde{\chi}_{F/AF}^0)=0$.

We focus on the transition temperature for weak repulsion, in which case it is numerically obtained that the transition temperature is proportional to $U^{N/(N-1)}$. In this case, we take account of only the two kinds of eigenstates whose eigenvalues are around E=0, i.e., $E=E_0^{(N+1)}=-E_0^{(N)}\simeq A_N|k-\pi/a|^N$ with A_N being a positive constant. Eigenfunctions of such states are known to be well localized around the zigzag edges, which are explicitly shown in Fig. 5. At the sufficiently low temperature, owing to the localized nature of the eigenfunctions, the matrix elements of $\tilde{\chi}_{F/AF}^0$ can be neglected except $[\tilde{\chi}_{F/AF}^0]_{11}$, which are calculated as follows,

$$[\tilde{\chi}_F^0]_{11} \simeq -\frac{2}{N_L} \sum_k \frac{\partial f}{\partial \epsilon} \bigg|_{\epsilon = E_0^{(N+1)}(k)} = 2 \int_0^\infty d\epsilon \left\{ -\frac{\partial f}{\partial \epsilon} \right\} D_N(\epsilon),$$
 (21)

$$[\tilde{\chi}_{AF}^{0}]_{11} \simeq -\frac{2}{N_L} \sum_{k} \frac{f(\epsilon) - f(-\epsilon)}{2\epsilon} \bigg|_{\epsilon = E_{\alpha}^{(N+1)}(k)} = 2 \int_{0}^{\infty} d\epsilon \left\{ \frac{f(-\epsilon) - f(\epsilon)}{2\epsilon} \right\} D_N(\epsilon). \tag{22}$$

Here, $D_N(\epsilon)$, which is the density of states close to $\epsilon=0$, is obtained as $D_N(\epsilon)\simeq C_N/|\epsilon|^{1-1/N-4)}$ from the asymptotic behaviour of the energy dispersion, $E_0^{(N+1)}=-E_0^{(N)}=A_N|k-\pi/a|^N$. In deriving eqs. (21) and (22), the amplitude at the zigzag edges are approximated as $\left[\vec{v}_0^{(j)}(k)\right]_1=\pm 1/\sqrt{2}$ and $\left[\vec{v}_0^{(j)}(k)\right]_{2N}=\pm 1/\sqrt{2}$ (j=N,N+1), and the others are discarded. In addition, the sign of two kinds of amplitudes are assigned according to the result in Fig. 5, e.g., in the odd N case, $\left[\vec{v}_0^{(N+1)}(k)\right]_1=1/\sqrt{2}$, $\left[\vec{v}_0^{(N+1)}(k)\right]_{2N}=-1/\sqrt{2}$, from Fig. 5 (a). The transition temperature $T_{c,F/AF}$, which is determined by $1-(U/2)[\tilde{\chi}_{F/AF}^0]_{11}=0$, is obtained as follows;

$$T_{c,F} = (C_N X_{F,N} U)^{N/(N-1)},$$
 (23)

$$T_{c,AF} = (C_N X_{AF,N} U)^{N/(N-1)},$$
 (24)

where $X_{\mathrm{F/AF},N}$ is an constant depending on the width N,

$$X_{F,N} = \int_0^\infty dx \frac{1}{e^x + 1} \frac{1}{e^{-x} + 1} \frac{1}{x^{1-1/N}},$$
(25)

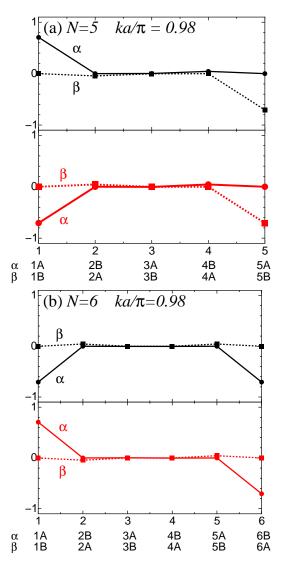


Fig. 5. (Color online) Amplitudes of the eigenfunctions in the transverse direction close to E/t=0 for N=5 (a) and N=6 (b) where $ka/\pi=0.98$ is used. In the respective figure, the upper and lower graph express the wavefunction of the conduction band and of the valence band, respectively. The slices α and β in the unit cell are defined in Fig. 1.

$$X_{\text{AF},N} = \int_0^\infty dx \frac{1}{e^x + 1} \frac{1}{e^{-x} + 1} \frac{1}{x^{1 - 1/N}} \frac{\sinh x}{x}.$$
 (26)

Thus the transition temperatures of the both magnetic states are proportional to $U^{N/(N-1)}$; the result for $T_{c,\mathrm{AF}}$ is identical with that obtained by the numerical calculation. Note that $T_{c,\mathrm{AF}} > T_{c,\mathrm{F}}$ because of $X_{\mathrm{AF},N} > X_{\mathrm{F},N}$, which corresponds to the fact that the antiferromagnetic state is more stable than the ferromagnetic state.

Finally, we discuss the case where the hopping integral at the 1st leg and that of the N-th one are modified as $c \times t$ and $c' \times t$, respectively. In this case, the matrix elements of $h_k(k)$ in eq. (5) are changed as $[h_k(k)]_{1,2} = [h_k(k)]_{2,1} = -ct\gamma_k$ and $[h_k(k)]_{2N-1,2N} = [h_k(k)]_{2N,2N-1} = -c't\gamma_k$. Even

upon such a change, the power of the energy dispersion chose to E=0 is not changed; i.e., the energy dispersion is given by $E_0^{(N+1)}=-E_0^{(N)}\sim A_N(c,c')|k-\pi/a|^N$ as is shown in Fig. 6. The power-law

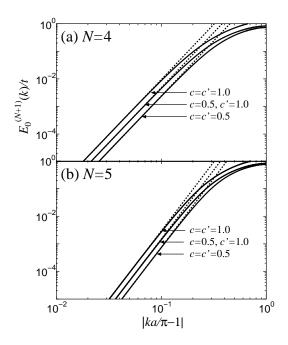


Fig. 6. Energy dispersion $E_0^{(N+1)}(k)$ $(=-E_0^{(N)}(k))$ close to $k=\pi/a$ for several choices of c and c' in the case of N=4 (a) and N=5 (b). Here, the hopping at the 1st leg and at the N-th leg (see Fig. 1) are modified as $c\times t$ and $c'\times t$, respectively. In each figure, the dotted line express the fitting by using $E_0^{(N+1)}(k)\propto |k-\pi/a|^N$.

dependence of the magnetic moment at the edge $m_{1A} \propto U^{1/(N-1)}$ should be observed even in the present situation if the anomalous power-law dependence of the magnetic moments and of the critical temperature discussed above are originated from the dispersion relation close to E/t=0. In Fig. 7, we show the magnetic moments at the 1A site of the AF state at T=0 for the N=4 and N=5 system as a function of U/t for several choices of c and c'. Here, the power-law dependence $m_{1A} \propto U^{1/(N-1)}$ is observed even if the hopping integrals at the edges are modified. The result is the strong evidence that the anomalous power-law dependence found in the present work is originated from the power-law dependence of the energy dispersion close to E/t=0. We note that the magnetic moments at the edges does not satisfy the simple relation $m_{1A}=-m_{NB}$ and are obtained as $m_{1A}>|m_{NB}|$ in the asymmetric case with c< c' though the total magnetic moment in the unit cell vanishes. Even in such a case, as long as $U/t \ll 1$, $|m_{NB}|$ is also proportional to $U^{1/(N-1)}$ as well as m_{1A} .

4. Summary

In the present work, we applied the mean-field approximation to the Hubbard model on the zigzag GNR and studied properties of the magnetic ordered states. The spontaneous magnetic moments at the

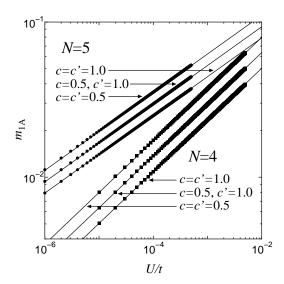


Fig. 7. Spontaneous magnetic moment at the 1A site (upper zigzag edge in Fig. 1) m_{1A} of the AF state with N=4 and N=5 at T=0 as a function of U/t for several choices of c and c'. The solid lines express the fitting by $m_{1A} \propto U^{1/(N-1)}$.

zigzag edges and the transition temperature of the AF state were investigated in detail as a function of on-site repulsion U for $U/t \ll 1$.

We can obtain the two kinds of the ordered states; one is the AF state satisfying $m_{iA} = -m_{(N-i+1)B}$ and the other is the F state with $m_{iA} = m_{(N-i+1)B}$. The AF state is more stable than the F state though the energy difference per one carbon atom between the two magnetic ordered states becomes smaller with increasing the width N. Therefore, the AF state was investigated in detail. Due to existence of the states localized around the zigzag edges close to Fermi energy, the magnetic moments at the zigzag edges are far bigger than the others for $U/t \ll 1$, and show characteristic U/t dependence as $m_{1A} \propto (U/t)^{1/(N-1)}$. Also, the transition temperature $T_{c,AF}$ shows the power-law dependence $T_{c,AF} \propto (U/t)^{N/(N-1)}$, which is analytically demonstrated from the divergence of the corresponding susceptibility. Discrepancy in the power of m_{1A} and $T_{c,AF}$ can be well understood by considering that the AF transition is dominated by the edge states and by assuming the simple dimension analysis, $T_{c,AF} \propto U \times m_{1A}$. Therefore, we can conclude that the both anomalous U/t dependences are originated from the power-law divergence of the DOS close to Fermi energy. Actually, the power-law dependence of the magnetic moment at the edges are observed if the hopping integrals at the zigzag edges are modified, where the power of the DOS is unchanged.

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